Amendments to the Claims

- 1. (Currently Amended) An electronic device comprising a free-standing thin film (30), the thin film (30) comprising an alloy of aluminum and at least magnesium.
- 2. (Original) An electronic device as claimed in claim 1, comprising an alloy of aluminum, magnesium and at least one further material.
- 3. (Original) An electronic device as claimed in Claim 2, wherein said at least one further material comprises one or more of copper, manganese, silicon, nickel, chromium, and lithium.
- 4. (Currently Amended) An electronic device as claimed in Claim 1,2 or 3claim 1, wherein the Mg content is between 0.1 and 10 atomic weight per cent.
- 5. (Original) An electronic device as claimed in Claim 3, wherein said one further material comprises copper in an amount between 0.1 and 8 atomic weight per cent.
- 6. (Currently Amended) An electronic device as claimed in Claim 3 or 5 claim 3, wherein the sum of the contents of magnesium, copper and manganese is between 2.5 and 10 atomic weight per cent.
- 7. (Currently Amended) An electronic device as claimed in Claim 3 or 6claim 3, wherein the alloy is chosen from the group of $A1_vMg_wCu_xMn_y$, $A1_vMg_wMn_y$, $A1_vMg_wCu_xSi_{z1}Ni_{z2}$, $A1_vMg_wCu_x$, $A1_vMg_wCu_xSi_{z1}$, $A1_vMg_wCu_xZn_{z3}Cr_{z4}$, $A1_vMg_wCu_xLi_{z5}$, with $80 \le v \le 99.8$; and $0.1 \le w \le 8.0$, $0.1 \le x \le 8.0$, $0.1 \le y \le 4.0$ and z1, z2, z3, z4, z5 each smaller than 20, and preferably smaller than 5.
- 8. (Currently Amended) A method of manufacturing an electronic device comprising a free-standing thin film (30), the method comprising the steps of:

 providing a mechanical layer of material (12) on a sacrificial release layer (16,17);

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- structuring said mechanical layer (12) to define the film (30); and
- removing said release layer (16, 17) to render said film (30) freestanding, characterized in that said top layer comprises an alloy of aluminum and at least magnesium.
- 9. (Currently Amended) A method according to claim 8, wherein said release layer (16, 17) is patterned prior to provision of said mechanical layer (12) thereon.